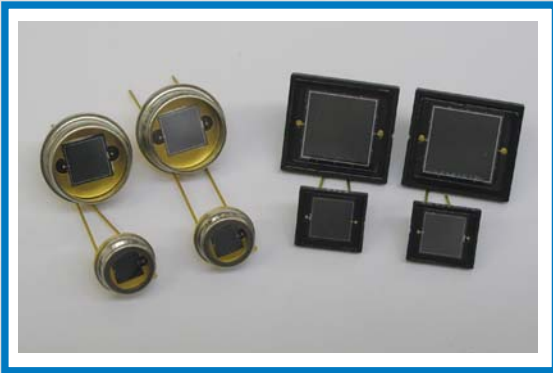




OSI optoelectronics introduces new family of Planar Diffused UV Enhanced Photodiode: the UV-EQ and UV-EQC Series. The new Silicon is processed for enhanced responsivity over 200-400nm and sensitivity down to 190 nm. Their response in NIR region has been suppressed. The EK series offer hermetic package alternative at a lower cost and is sensitive down to 320nm.

These detectors can be reverse biased for lower capacitance, faster response, and wider dynamic range applications. They are ideal for UV Spectrophotometer, Analytical Instruments, and Medical Instrumentation.

FEATURES

- Excellent UV Sensitivity
- Suppressed NIR Response
- High Shunt Resistance

APPLICATIONS

- Spectrophotometer
- Analytical Instruments
- Medical Instrument



Typical Electro-Optical Specifications at T_A = 23° C

Model Number	Active Area		Peak Wavelength (nm)	Responsivity (A/W)			Capacitance (pF)	Shunt Resistance (GOhm)		NEP (W/sqrtHz)	Reverse Voltage (V)	Rise Time (us)	Temp. Range (°C)		Package Style	
	Area (mm²)	Dimension (mm)		200 nm	633 nm	720 nm		0V	-10mV				0V 200nm	0V 1KOhm		Operating
				typ.	typ.	typ.		typ.	typ.			min.	typ.	typ.		max
Metal Package, Quartz Window																
UV-005EQ	5.7	2.4 x 2.4	720	0.12	0.34	0.36	140	2	20	8.2 E-15	5	0.5	-20 ~ +60	-55 ~ +80	2 / T05	
UV-013EQ	13	3.6 x 3.6					280	1	10	1.1 E-14		1			2 / T05	
UV-035EQ	34	5.8 x 5.8					800	0.5	5	1.6 E-14		2			3 / T08	
Ceramic Package, Quartz Window																
UV-005EQC	5.7	2.4 x 2.4	720	0.12	0.34	0.36	140	2	20	8.2E-15	5	0.5	-20 ~ +60	-20 ~ +80	4 / Ceramic	
UV-035EQC	34	5.8 x 5.8					800	0.5	5	1.6 E-14		2				
UV-100EQC	100	10 x 10					2500	0.2	2	2.6E-14		7				
Metal Package, Borosilicate Window¶																
UV-005EK	5.7	2.4 x 2.4	720	--	0.34	0.36	140	2	20	8.2 E-15*	5	0.5	-40 ~ +100	-55 ~ +125	2 / T05	
UV-013EK	13	3.6 x 3.6					280	1	10	1.1 E-14*		1			2 / T05	
UV-035EK	34	5.8 x 5.8					800	0.5	5	1.6 E-14*		2			3 / T08	

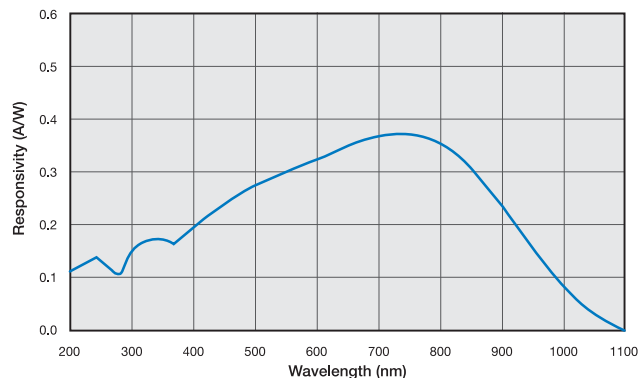
*) NEP is calculated using typical responsivity 0.12 A/W at 320nm

¶) Sensitivity range: 320-1100 nm

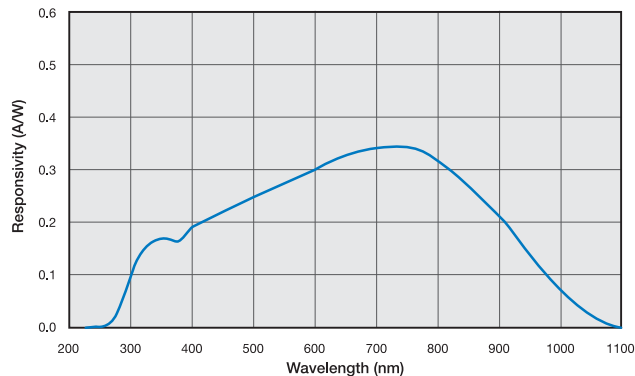
UV-EQ / EQC / EK SERIES

UV Enhanced, Suppressed NIR Photodiode

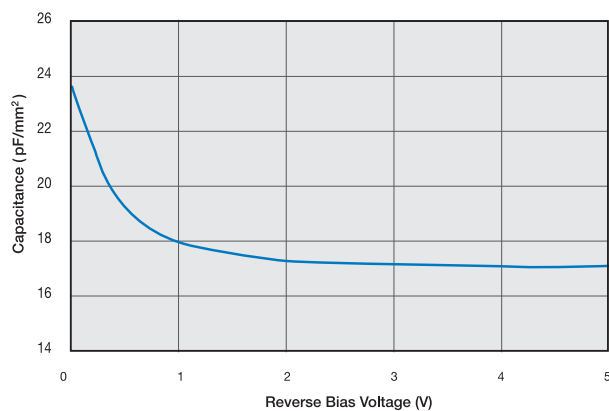
■ Typ. Responsivity with Quartz Window ($T_A = 25^\circ\text{C}$)



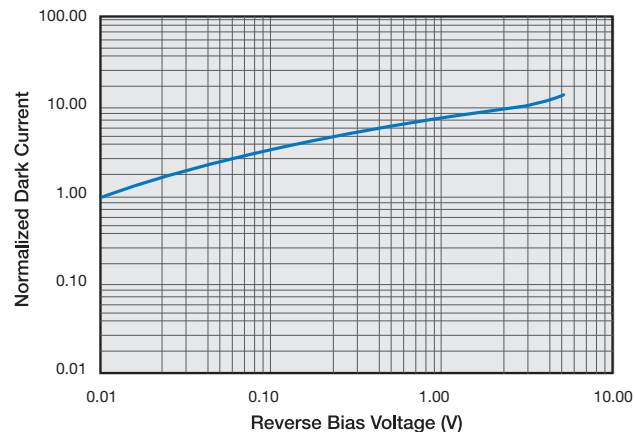
■ Typ. Responsivity with Borosilicate Window ($T_A = 25^\circ\text{C}$)



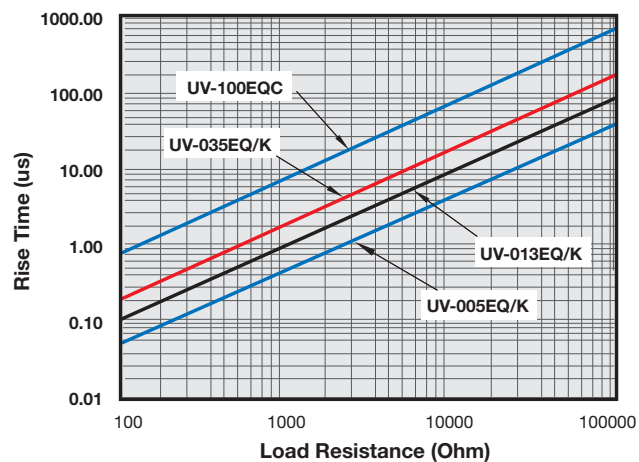
■ Typ. Capacitance vs. Reverse Bias ($T_A = 25^\circ\text{C}$)



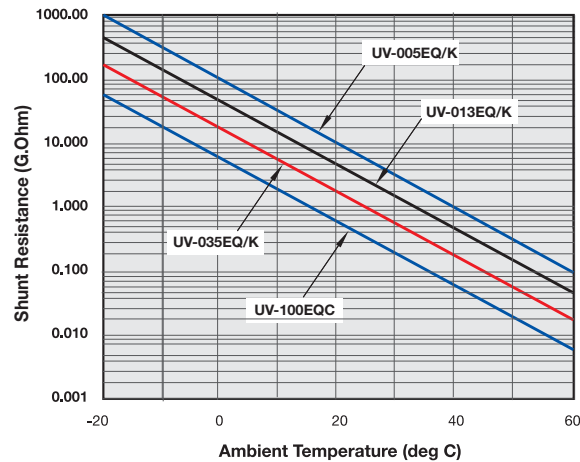
■ Typ. Dark Current vs. Reverse Bias ($T_A = 25^\circ\text{C}$, Normalized at -0.01V)



■ Typ. Rise Time vs. Load Resistance ($T_A = 25^\circ\text{C}$, $V_R = 0\text{V}$)



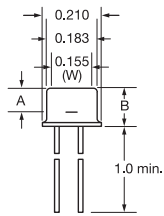
■ Typ. Shunt Resistance vs. Ambient Temperature



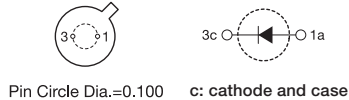
MECHANICAL SPECIFICATIONS

All units in inches. Pinouts are bottom view.

1 TO-18

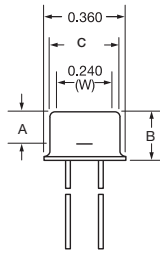


Products:
UV-001D

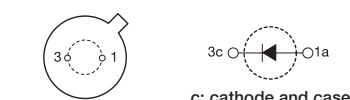


Model #	A	B
UV-001D	0.080	0.200

2 TO-5

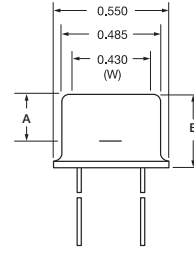


Products:
UV-005D
UV-013D
UV-005E
UV-013E
UV-005DQ/K
UV-013DQ/K
UV-005EQ/K
UV-013EQ/K

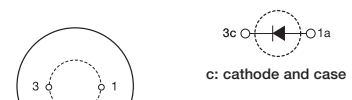


Model #	A	B	C
UV-xxxD	0.102	0.180	0.325
UV-xxxE	0.102	0.180	0.325
UV-xxxDQ/K	0.065	0.138	0.320
UV-xxxEQ/K	0.055	0.138	0.320

3 TO-8

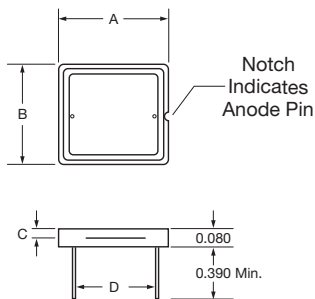


Products:
UV-035D
UV-035E
UV-035DQ/K
UV-035EQ/K



Model #	A	B
UV-035D	0.140	0.205
UV-035E	0.140	0.205
UV-035DQ/K	0.130	0.195
UV-035EQ/K	0.120	0.195

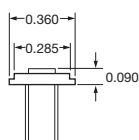
4 Ceramic



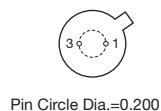
P/N	A	B	C	D
UV-005EC	0.400	0.350	0.030	0.290
UV-035EC	0.400	0.350	0.030	0.290
UV-100EC	0.650	0.590	0.050	0.500
UV-005DC	0.400	0.350	0.030	0.290
UV-035DC	0.400	0.350	0.030	0.290
UV-100DC	0.650	0.590	0.050	0.500
XUV-50C	0.650	0.590	0.027	0.490
XUV-100C	0.650	0.590	0.027	0.490

P/N	A	B	C	D
UV-005EQC	0.300	0.236	0.024	0.177
UV-035EQC	0.400	0.350	0.028	0.290
UV-100EQC	0.650	0.590	0.028	0.500
UV-005DQC	0.300	0.236	0.035	0.177
UV-035DQC	0.400	0.350	0.039	0.290
UV-100DQC	0.650	0.590	0.039	0.500

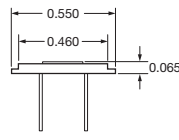
5 TO-5



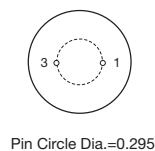
Products:
XUV-005



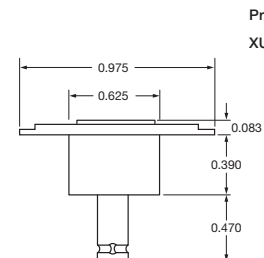
6 TO-8



Products:
XUV-020
XUV-035



7 BNC



Products:
XUV-100

BNC Connector
Outer Contact = Cathode